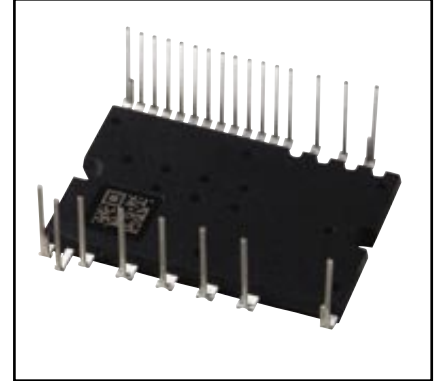
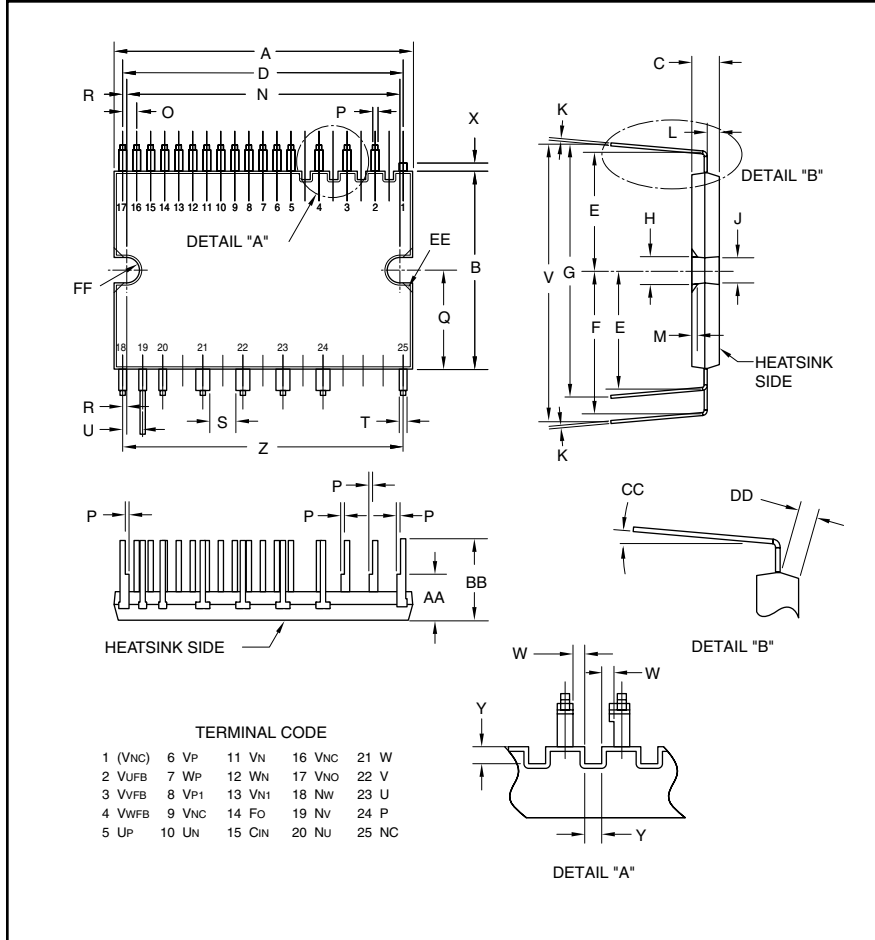


Intellimod™ Module Dual-In-Line Intelligent Power Module 20 Amperes/600 Volts



Description:

DIP-IPMs are intelligent power modules that integrate power devices, drivers, and protection circuitry in an ultra compact dual-in-line transfer-mold package for use in driving small three phase motors. Use of 5th generation IGBTs, DIP packaging, and application specific HVICs allow the designer to reduce inverter size and overall design time.

Features:

- Compact Packages
- Single Power Supply
- Integrated HVICs
- Direct Connection to CPU
- Reduced R_{th}

Applications:

- Refrigerators
- Air Conditioners
- Small Servo Motors
- Small Motor Control

Ordering Information:

PS21965-S is a 600V, 20 Ampere short pin DIP Intelligent Power Module.

Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	1.50±0.02	38.0±0.5
B	0.94±0.02	24.0±0.5
C	0.14	3.5
D	1.40	35.56
E	0.57±0.02	14.4±0.5
F	0.74±0.02	18.9±0.5
G	1.15±0.02	29.2±0.5
H	0.14	3.5
J	0.13	3.3
K	0.016	0.4
L	0.06±0.02	1.5±0.05
M	0.031	0.8
N	1.39±0.019	35.0±0.3
O	0.07±0.008	1.778±0.2
P	0.02	0.5
Q	0.47	12.0

Dimensions	Inches	Millimeters
R	0.011	0.28
S	0.12	3.08
T	0.024	0.6
U	0.1±0.008	2.54±0.2
V	1.33±0.02	33.7±0.5
W	0.03	0.678
X	0.04	1.0
Y	0.05	1.2
Z	1.40	35.56
AA	0.22±0.02	5.5±0.5
BB	0.37±0.02	9.5±0.5
CC	0 ~ 5°	0 ~ 5°
DD	0.06 MIN.	1.5 Min.
EE	0.05	1.2
FF	0.063 Rad.	1.6 Rad.

PS21965-S
Intellimod™ Module
Dual-In-Line Intelligent Power Module
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Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	PS21965-S	Units
Power Device Junction Temperature*	T_j	-20 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Case Operating Temperature (Note 1)	T_C	-20 to 100	$^\circ\text{C}$
Mounting Torque, M3 Mounting Screws	—	6.9	in-lb
Module Weight (Typical)	—	10	Grams
Heatsink Flatness (Note 2)	—	-50 to 100	μm
Self-protection Supply Voltage Limit (Short Circuit Protection Capability)**	$V_{CC(prot.)}$	400	Volts
Isolation Voltage, AC 1 minute, 60Hz Sinusoidal, Connection Pins to Heatsink Plate	V_{ISO}	1500	Volts

*The maximum junction temperature rating of the power chips integrated within the DIP-IPM is 150°C ($@T_C \leq 100^\circ\text{C}$). However, to ensure safe operation of the DIP-IPM, the average junction temperature should be limited to $T_{j(avg)} \leq 125^\circ\text{C}$ ($@T_C \leq 100^\circ\text{C}$).

** $V_D = 13.5 - 16.5\text{V}$, Inverter Part, $T_j = 125^\circ\text{C}$, Non-repetitive, Less than $2\mu\text{s}$

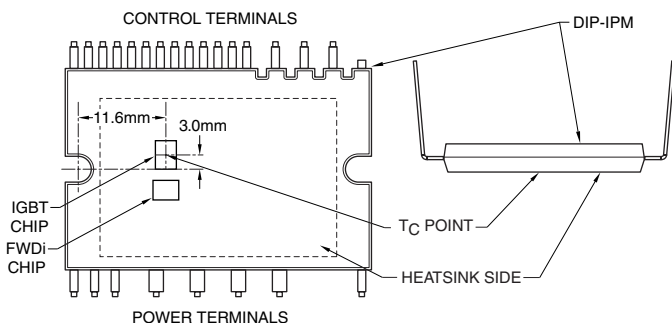
IGBT Inverter Sector

Collector-Emitter Voltage	V_{CES}	600	Volts
Each Collector Current, \pm ($T_C = 25^\circ\text{C}$)	I_C	20	Amperes
Each Peak Collector Current, \pm ($T_C = 25^\circ\text{C}$, Less than 1ms)	I_{CP}	40	Amperes
Supply Voltage (Applied between P - N)	V_{CC}	450	Volts
Supply Voltage, Surge (Applied between P - N)	$V_{CC(surge)}$	500	Volts
Collector Dissipation ($T_C = 25^\circ\text{C}$, per 1 Chip)	P_C	35.7	Watts

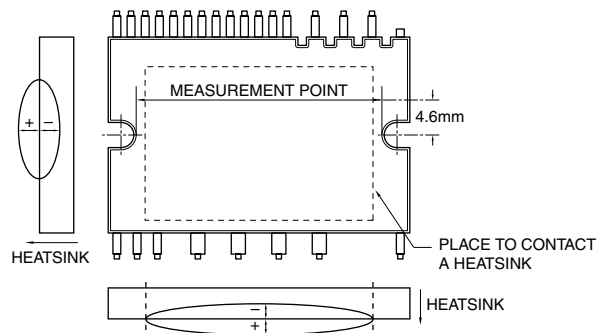
Control Sector

Supply Voltage (Applied between $V_{P1-V_{NC}}$, $V_{N1-V_{NC}}$)	V_D	20	Volts
Supply Voltage (Applied between V_{UFB-U} , V_{VFB-V} , V_{WFB-W})	V_{DB}	20	Volts
Input Voltage (Applied between U_P, V_P, W_P-V_{NC} ; U_N, V_N, W_N-V_{NC})	V_{IN}	-0.5 ~ $V_D+0.5$	Volts
Fault Output Supply Voltage (Applied between F_O-V_{NC})	V_{FO}	-0.5 ~ $V_D+0.5$	Volts
Fault Output Current (Sink Current at F_O Terminal)	I_{FO}	1	mA
Current Sensing Input Voltage (Applied between $C_{IN-V_{NC}}$)	V_{SC}	-0.5 ~ $V_D+0.5$	Volts

Note 1 – T_C Measure Point



Note 2 – Flatness Measurement Position





Powerex, Inc., 173 Pavilion Lane, Youngwood, Pennsylvania 15697 (724) 925-7272

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Electrical and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
IGBT Inverter Sector						
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_D = V_{DB} = 15\text{V}, I_C = 20\text{A}, V_{IN} = 5\text{V}, T_j = 25^\circ\text{C}$	—	1.70	2.20	Volts
		$V_D = V_{DB} = 15\text{V}, I_C = 20\text{A}, V_{IN} = 5\text{V}, T_j = 125^\circ\text{C}$	—	1.80	2.30	Volts
Diode Forward Voltage	V_{EC}	$-I_C = 20\text{A}, V_{IN} = 0\text{V}$	—	1.90	2.40	Volts
Inductive Load Switching Times	t_{on}		0.70	1.30	1.90	μS
	t_{rr}	$V_{CC} = 300\text{V}, V_D = V_{DB} = 15\text{V},$	—	0.30	—	μS
	$t_{C(on)}$	$I_C = 20\text{A}, T_j = 125^\circ\text{C},$	—	0.50	0.75	μS
	t_{off}	$V_{IN} = 0 \Leftrightarrow 5\text{V}, \text{Inductive Load},$	—	1.60	2.20	μS
	$t_{C(off)}$		—	0.40	0.75	μS
Collector Cutoff Current	I_{CES}	$V_{CE} = V_{CES}, T_j = 25^\circ\text{C}$	—	—	1.0	mA
		$V_{CE} = V_{CES}, T_j = 125^\circ\text{C}$	—	—	10	mA

Control Sector

Circuit Current $V_D = V_{DB} = 15\text{V}$	I_D	$V_{IN} = 5\text{V}$	Total of $V_{P1-V_{NC}}, V_{N1-V_{NC}}$	—	—	2.80	mA
			$V_{UFB-U}, V_{VFB-V}, V_{WFB-W}$	—	—	0.55	mA
		$V_{IN} = 0\text{V}$	Total of $V_{P1-V_{NC}}, V_{N1-V_{NC}}$	—	—	2.80	mA
			$V_{UFB-U}, V_{VFB-V}, V_{WFB-W}$	—	—	0.55	mA
Fault Output Voltage	V_{FOH}	$V_{SC} = 0\text{V}, F_O \text{ Terminal Pull-up to } 5\text{V by } 10\text{k}\Omega$	4.9	—	—	Volts	
	V_{FOL}	$V_{SC} = 1\text{V}, I_{FO} = 1\text{mA}$	—	—	0.95	Volts	
Input Current	I_{IN}	$V_{IN} = 5\text{V}$	0.70	1.00	1.50	mA	
Short Circuit Trip Level*	$V_{SC(ref)}$	$V_D = 15\text{V}^*$	0.43	0.48	0.53	Volts	
Supply Circuit Under-voltage	UV_{DBt}	Trip Level, $T_j \leq 125^\circ\text{C}$	10.0	—	12.0	Volts	
	UV_{DBr}	Reset Level, $T_j \leq 125^\circ\text{C}$	10.5	—	12.5	Volts	
	UV_{Dt}	Trip Level, $T_j \leq 125^\circ\text{C}$	10.3	—	12.5	Volts	
	UV_{Dr}	Reset Level, $T_j \leq 125^\circ\text{C}$	10.8	—	13.0	Volts	
Fault Output Pulse Width**	t_{FO}		20	—	—	μs	
ON Threshold Voltage	$V_{th(on)}$	Applied between	—	2.1	2.6	Volts	
OFF Threshold Voltage	$V_{th(off)}$	$U_P, V_P, W_P-V_{NC},$	0.8	1.3	—	Volts	
ON/OFF Threshold Hysteresis Voltage	$V_{th(hys)}$	U_N, V_N, W_N-V_{NC}	0.35	0.65	—	Volts	

* Short Circuit protection is functioning only for the low-arms. Please select the value of the external shunt resistor such that the S_C trip level is less than 1.7 times the current rating.

**Fault signal is asserted only for a U_V or S_C condition on the low side. On a S_C fault the F_O duration will be 20 μsec . On a U_V condition the fault signal will be asserted as long as the U_V condition exists or for 20 μsec , whichever is longer.



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Thermal Characteristics

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case	$R_{th(j-c)Q}$	Inverter IGBT (Per 1/6 Module)	—	—	2.8	°C/Watt
	$R_{th(j-c)D}$	Inverter FWDi (Per 1/6 Module)	—	—	3.9	°C/Watt

Recommended Conditions for Use

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Supply Voltage	V_{CC}	Applied between P-N Terminals	0	300	400	Volts
Control Supply Voltage	V_D	Applied between V_{P1} - V_{NC} , V_{N1} - V_{NC}	13.5	15.0	16.5	Volts
	V_{DB}	Applied between V_{UFB-U} , V_{VFB-V} , V_{WFB-W}	13.0	15.0	18.5	Volts
Control Supply Variation	dV_D , dV_{DB}		-1	—	1	V/ μ s
Arm Shoot-through Blocking Time	t_{DEAD}	For Each Input Signal, $T_C \leq 100^\circ\text{C}$	1.5	—	—	μ s
Output r.m.s. Current*	I_O $f_{PWM} = 5\text{kHz}$	$V_{CC} = 300\text{V}$, $V_D = V_{DB} = 15\text{V}$, P.F. = 0.8, Sinusoidal PWM, $T_j \leq 125^\circ\text{C}$, $T_C \leq 100^\circ\text{C}$	—	—	10.0	A_{rms}
	I_O $f_{PWM} = 15\text{kHz}$		—	—	6.0	A_{rms}
Allowable Minimum Input	$P_{WIN(on)}$		0.5	—	—	μ s
Pulse Width**	$P_{WIN(off)}$		0.5	—	—	μ s
V_{NC} Voltage Variation	V_{NC}	Between V_{NC-N} (Including Surge)	-5.0	—	5.0	Volts

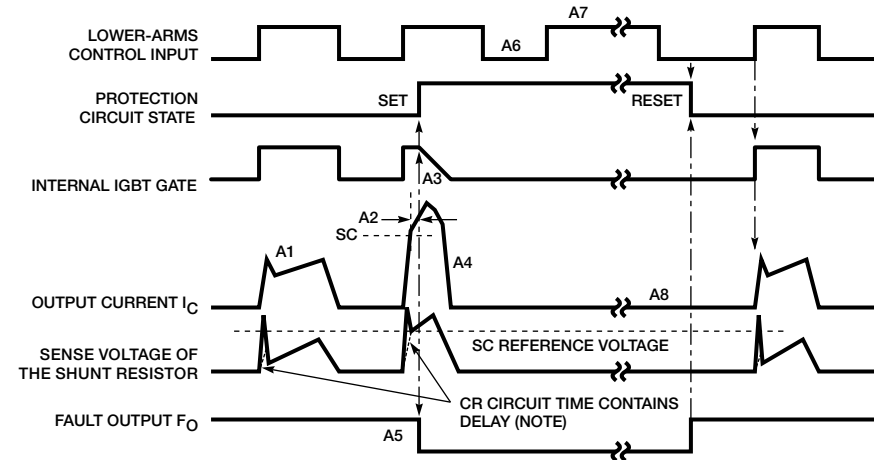
*The allowable r.m.s. current also depends on the actual application conditions.

**DIP-IPM might not make response or work properly if the input signal pulse width is less than the recommended minimum value.

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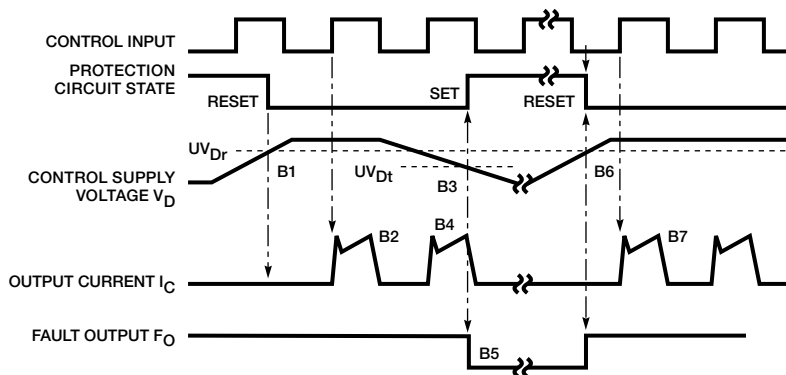
Protection Function Timing Diagrams

Short-Circuit Protection (Lower-arms only with the external shunt resistor and RC filter)



- A1: Normal operation – IGBT turn on and conducting current.
- A2: Short-circuit current detected (SC trigger).
- A3: IGBT gate hard interrupted.
- A4: IGBT turn off.
- A5: F_O output with a fixed pulse width of $t_{FO(min)} = 20\mu s$.
- A6: Input “L” – IGBT off.
- A7: Input “H” – IGBT on is blocked during the F_O output period.
- A8: IGBT stays in off state.

Under-Voltage Protection (Lower-side, UV_D)

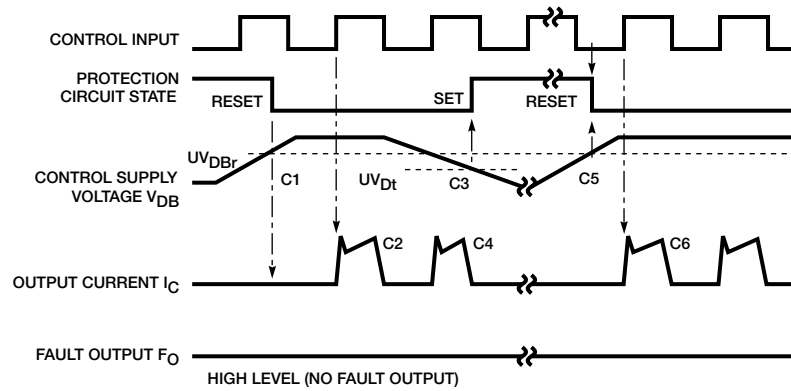


- B1: Control supply voltage rise – After the voltage level reaches UV_{Dr} , the drive circuit begins to work at the rising edge of the next input signal.
- B2: Normal operation – IGBT turn on and conducting current.
- B3: Under-voltage trip (UV_{Dt}).
- B4: IGBT turn off regardless of the control input level.
- B5: F_O output during under-voltage period, however, the minimum pulse width is $20\mu s$.
- B6: Under-voltage reset (UV_{Dr}).
- B7: Normal operation – IGBT turn on and conducting current.

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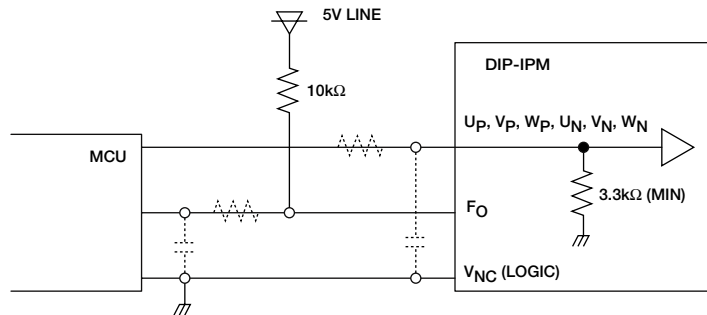
Protection Function Timing Diagrams

Under-Voltage Protection (Upper-side, UV_{DB})



- C1: Control supply voltage rises – After the voltage level reaches UV_{DBr} , the drive circuit begins to work at the rising edge of the next input signal.
- C2: Normal operation – IGBT turn on and conducting current.
- C3: Under-voltage trip (UV_{DBt}).
- C4: IGBT stays off regardless of the control input level, but there is no F_O signal output.
- C5: Under-voltage reset (UV_{Dr}).
- C6: Normal operation – IGBT turn on and conducting current.

Typical Interface Circuit



NOTE: RC coupling at each input (parts shown dotted) may change depending on the PWM control scheme used in the application and the wiring impedance of the printed circuit board. The DIP-IPM input signal section integrates a $3.3k\Omega$ (min) pull-down resistor. Therefore, when using an external filtering resistor, care must be taken to satisfy the turn-on threshold voltage requirement.

Wiring Method Around Shunt Resistor

